CLAIMS

1. A structured material composed by including a noble metal, comprising an oriented layer formed on a layer containing a Group 4A metal.

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- 2. The structured material according to claim 1, wherein said layer containing the Group 4A metal is provided on a MgO (001) layer.
- 3. The structured material according to claim 1, wherein said layer containing the Group 4A metal has a thickness within a range of from 0.1 to 3.0 nm.
- 4. The structured material according to claim 1,
 15 wherein said noble metal is Pt, Pd, Ir, Rh, Ag or a
 combination thereof.
- The structured material according to claim 1, wherein said layer containing the Group 4A metal is a
 Ti layer, a Zr layer, a Hf layer or a layer constituted of a combination of these metals.
- 6. The structured material according to claim 2, wherein said layer containing the Group 4A metal is dispersed in the shape of islands on said MgO (001) layer.

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- 7. A magnetic recording medium characterized in including, on a substrate and in order from the substrate side, a MgO (001) layer, a layer containing a Group4A metal, an oriented layer, and a recording layer.
- 8. A magnetic recording/reproducing apparatus comprising:
- a magnetic head capable of a conducting

 10 magnetic recording on a magnetic recording medium

 comprising, on a substrate and in order from the

 substrate side, a MgO (001) layer, a layer containing

 a Group 4A metal, an oriented layer, and a recording

 layer; and
- a magnetic head driving section for driving said magnetic head.
 - 9. A method for producing a structured material comprising:
- a first step of preparing a member having a MgO (001) layer;
 - a second step of forming a layer containing a Group 4A metal on said MgO (001) layer; and
- a third step of forming an oriented layer

 25 composed by containing a noble metal on said layer

 containing the Group 4A metal.

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10. The method for producing a structured material according to claim 9, wherein said third step is executed with the temperature of said layer containing the Group 4A metal being equal to or higher than 250°C but lower than 600°C.

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